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	othe Director of the U.S. Pater	at and Trader			nt.	
			103	519434	11.	
1.	Name of conveying pa Yoshio INOUE	irty(ies):		TE		
2.	Name and Address of	receiving part	y(ies):	200	100 A	
	FUJITSU MICROEL 7-1, Nishi-Shinjuku	2-chome,	LIMITED	AUG 0 8 20	. E	
	Shinjuku-ku, Tokyo JAPAN	163-0722		THE TRUBE	A STATE OF THE STA	
3.	Nature of conveyance  X Assignment Security Agre			lerger hange of Name		
	Other: Execution Date(s): <u>Ju</u>	ly 3, 2008				
4.	Application number(s)  This document is			w application.		
	OR  This document is  (a) Patent Application  (b) Patent No(s).	ation No(s). <u>12</u>		pplication: August 8, 2008; c	) r	
5.	Name and address of party to whom correspondence concerning document should be mailed: STAAS & HALSEY LLP Our Docket: 2127.1001  Attention: Paul I. Kravetz 1201 New York Ave., N.W., 7th Floor Washington, D.C. 20005					
6.	Total number of appli					
7.	Total fee (37 CFR 3.41)(\$ 40.00 per Patent or Application in Assignment)  ☐ Enclosed ☐ Authorized to be charged to deposit account.					
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Revised January, 2005

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## **U.S. ASSIGNMENT**

IN CONSIDERATION of the sum of One Dollar (\$1.0 inventor(s) (hereinafter, "ASSIGNOR") by (Insert Name(s) & Address(es) of ASSIGNEE(S)) FUJITSU MICROELECTRONICS LIMITED	00), and of other good and valuable	consideration paid to the undersigned
7-1, Nishi-Shinjuku 2-chome, Shinjuku-ku, Tokyo 163-07	22 Japan	
(hereinafter, "ASSIGNEE"), the receipt of which is hereby a ASSIGNEE the entire and exclusive right, title and interest to (Title of Invention) SEMICONDUCTOR DEVICE, CONTROL METHI	o the invention entitled	
INFORMATION GENERATING METHOD FOR S	SEMICONDUCTOR DEVICE	
relating to International Patent Application PCT/JP / executed on even date herewith or, if not so executed, was:	and/or for which application	for Letters Patent of the United States was
(a) executed on;	(Insert date of execution of appl	ication, if not concurrent)
(b) filed on  Serial No/;	Assignee's attorney is hereb data, when known.	y authorized to insert in (b) the specified
and to said application and all Letters Patent(s) of the Unite substitute, reissue or reexamination application based thereo including any extensions thereof (collectively, hereinafter,	n, for the full term or terms for which the said application(s) and Letters Patent(s	e said Letters Fatchit(s) may be granted and ")").
The ASSIGNOR agree(s), when requested by said ASSI which the ASSIGNEE may deem necessary, desirable or exinctuding in the preparation and prosecution of said applica reexamination, or public use proceeding, and in any litigatio acts to include but not be limited to executing all papers, in sworn testimony, and obtaining and producing evidence.	pedient, for securing, maintaining and tion(s) and the issuance of said Letters in or other legal proceeding which may a cluding separate assignments and decla	Patent(s), in any interference, reissue, irise or be declared in relation to same, such rations, taking all rightful oaths, providing
IN WITNESS WHEREOF, the undersigned inventor(s)		
1) Yoshio Inoue (Signature)	Yoshio INOUE (Type Name)	Jol . 3 . 2008 (Date)
(Signature)	(1 ype Name)	
2)(Signature)	(Type Name)	(Date)
3)(Signature)	(Type Name)	(Date)
4)(Signature)	(Type Name)	(Date)
5)	(Type Name)	(Date)

PATENT REEL: 021382 FRAME: 0423

**RECORDED: 08/08/2008**